



30V P-CHANNEL ENHANCEMENT MODE MOSFET POWERDI[®]

Product Summary

V _{(BR)DSS}	R _{DS(ON)} max	I _D max T _A = 25°C
	17mΩ @ V_{GS} = -10V	-8.6A
-30V	25mΩ @ V _{GS} = -4.5V	-7.1A

Description and Applications

This MOSFET has been designed to minimize the on-state resistance $(R_{DS(on)})$ and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

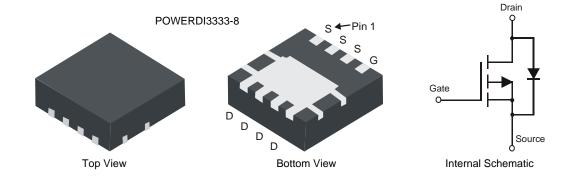
- Backlighting
- Power Management Functions
- DC-DC Converters

Features and Benefits

- Low R_{DS(ON)} ensures on state losses are minimized
- Small form factor thermally efficient package enables higher density end products
- Occupies just 33% of the board area occupied by SO-8 enabling smaller end product
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: POWERDI3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See diagram
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.008 grams (approximate)



Ordering Information (Note 4)

Part Number	Case	Packaging
DMP3008SFG-7	POWERDI3333-8	2000/Tape & Reel
DMP3008SFG-13	POWERDI3333-8	3000/Tape & Reel

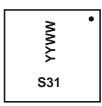
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com.

Marking Information

Notes:



S31 = Product Type Marking Code YYWW = Date Code Marking YY = Last digit of year (ex: 11 = 2011) WW = Week code (01 ~ 53)



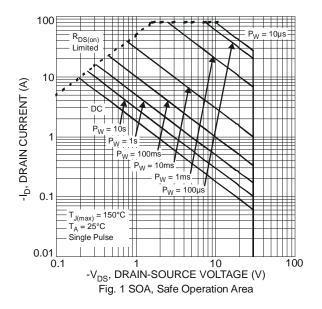
Maximum Ratings @T_A = 25°C unless otherwise specified

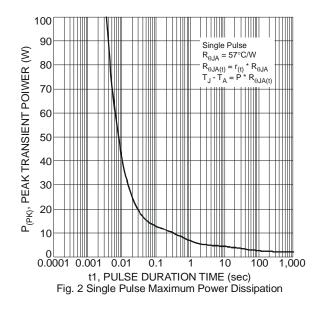
Characteristic	Symbol	Value	Units		
Drain-Source Voltage	V _{DSS}	-30	V		
Gate-Source Voltage			V _{GSS}	±20	V
Continuous Droin Current (Note 6) \/ 10\/	Steady State	T _A = 25°C T _A = 70°C	ID	-8.6 -7.0	А
Continuous Drain Current (Note 6) V _{GS} = -10V	t<10s	T _A = 25°C T _A = 70°C	ID	-11.7 -9.3	А
	Steady State	T _A = 25°C T _A = 70°C	ID	-7.1 -5.6	А
Continuous Drain Current (Note 6) $V_{GS} = -4.5V$	t<10s	T _A = 25°C T _A = 70°C	ID	-9.6 -7.6	А
Pulsed Drain Current (10µs pulse, duty cycle = 1%)	I _{DM}	-80	А		
Maximum Continuous Body Diode Forward Current (ls	-3.0	A		

Thermal Characteristics @T_A = 25°C unless otherwise specified

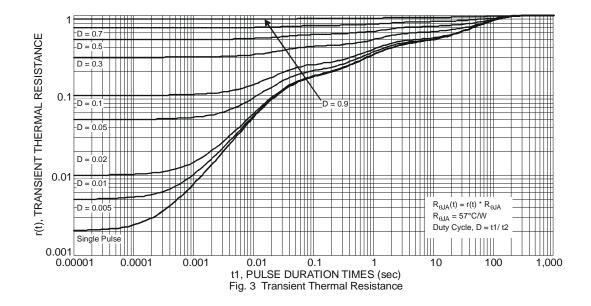
Characteristic	Symbol	Value	Units	
Total Power Dissipation (Note 5)		PD	0.9	W
Thermal Registence, Junction to Ambient (Note 5)	Steady state	D	140	°C/W
Thermal Resistance, Junction to Ambient (Note 5) t<10s		$R_{ extsf{ heta}JA}$	72	°C/W
Total Power Dissipation (Note 6)		PD	2.2	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady state	D	57	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	$R_{ extsf{ heta}JA}$	30	°C/W
Thermal Resistance, Junction to Case (Note 6)	$R_{\theta JC}$	7.1	°C/W	
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C

 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:









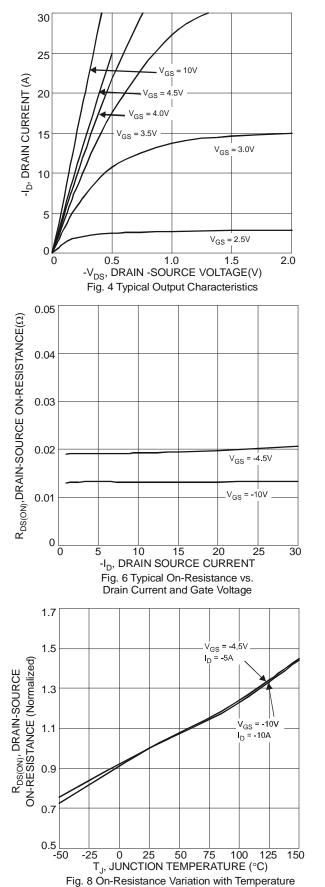
<u>Okana stanistia</u>	Symbol	Min	True	Max	11	Test Condition	
		Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)	<u> </u>		1	1	1		
Drain-Source Breakdown Voltage	BV _{DSS}	-30	—	—	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	_		-1.0	μA	$V_{DS} = -30V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(th)}	-1.1	-1.6	-2.1	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$	
Statia Drain Source On Desistance		_	12.5	17		V _{GS} = -10V, I _D = -10A	
Static Drain-Source On-Resistance	R _{DS} (ON)		18.5	25	mΩ	$V_{GS} = -4.5V, I_D = -10A$	
Forward Transfer Admittance	Y _{fs}	_	13		S	$V_{DS} = -15V, I_D = -10A$	
Diode Forward Voltage	V _{SD}	_	-0.7	-1.0	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	2230				
Output Capacitance	C _{oss}	_	328		pF	V _{DS} = -15V, V _{GS} = 0V f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	_	294	_		1 = 1.00012	
Gate Resistance	R _G	_	6.4		Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V _{GS} = -10V)	Qg	_	47	_			
Total Gate Charge (V _{GS} = -4.5V)	Qg	_	23		nC Vps = -15V lp = -10A		
Gate-Source Charge	Q _{gs}	_	9.4	_	ne	$V_{DS} = -15V, I_{D} = -10A$	
Gate-Drain Charge	Q _{gd}	_	5.6	_			
Turn-On Delay Time	t _{D(on)}	_	10.5				
Turn-On Rise Time	tr		8.5		n 0		
Turn-Off Delay Time	t _{D(off)}	_	90		ns	$V_{GS} = -10V, V_{DS} = -15V, R_G = 6\Omega$	
Turn-Off Fall Time	t _f	_	40				

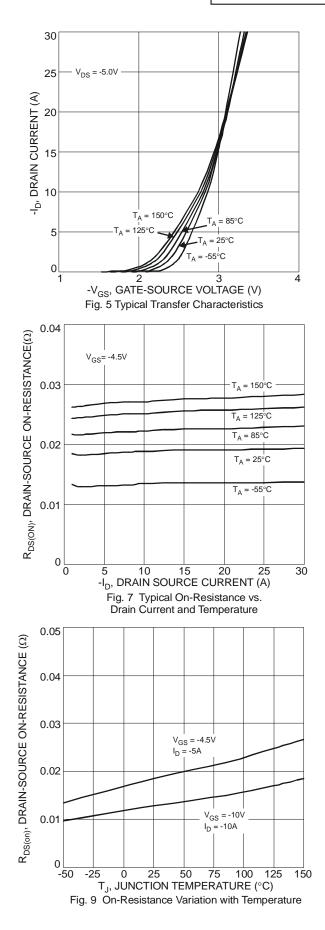
Notes: 7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.



DMP3008SFG

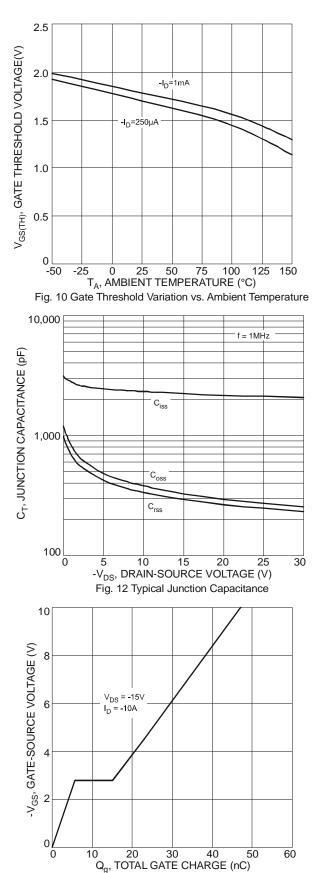


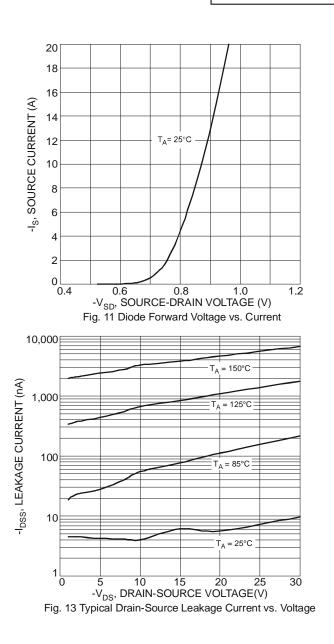


POWERDI is a registered trademark of Diodes Incorporated DMP3008SFG Document number: DS35598 Rev. 5 - 2

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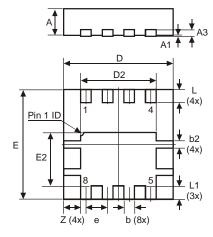


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Fig. 14 Gate-Charge Characteristics

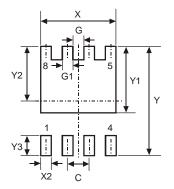


Package Outline Dimensions



POWERDI3333-8					
Dim	Min	Max	Тур		
D	3.25	3.35	3.30		
Е	3.25	3.35	3.30		
D2	2.22	2.32	2.27		
E2	1.56	1.66	1.61		
Α	0.75	0.85	0.80		
A1	0	0.05	0.02		
A3	-	-	0.203		
b	0.27	0.37	0.32		
b2	-	-	0.20		
L	0.35	0.45	0.40		
L1	_	_	0.39		
е	_	_	0.65		
Ζ	_	_	0.515		
All I	All Dimensions in mm				

Suggested Pad Layout



Dimensions	Value (in mm)			
С	0.650			
G	0.230			
G1	0.420			
Y	3.700			
Y1	2.250			
Y2	1.850			
Y3	0.700			
Х	2.370			
X2	0.420			



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